



SPECIFICATION

• Supplier : Samsung electro-mechanics • Samsung P/N : CL21A476MQYNNNG

• Product : Multi-layer Ceramic Capacitor • Description : CAP, 47 µF, 6.3V, ±20%, X5R, 0805

A. Samsung Part Number

<u>CL</u> <u>21</u> <u>A</u> <u>476</u> <u>M</u> <u>Q</u> <u>Y</u> <u>N</u> <u>N</u> <u>N</u> <u>G</u> ① ② ③ ④ ⑤ ⑥ ⑦ ⑧ ⑨ ⑩ ⑪

① Series	Samsung Multi-layer C	Samsung Multi-layer Ceramic Capacitor		
② Size	0805 (inch code)	L: 2.0 ± 0.2 mm	W: 1.25 ± 0.2 r	mm
③ Dielectric	X5R	8 Inner electrode	Ni	
4 Capacitance	47 μF	Termination	Cu	
⑤ Capacitance	±20 %	Plating	Sn 100% ((Pb Free)
tolerance		Product	Normal	
6 Rated Voltag	e 6.3 V	Special	Reserved for fu	uture use
7 Thickness	1.25 ± 0.2 mm	① Packaging	Embossed Typ	e, 7"reel(3,000ea)

B. Samsung Reliability Test and Judgement condition

	Performance	Test condition	
Capacitance	Within specified tolerance	120Hz ±20% 0.5±0.1Vrms	
Tan δ (DF)	0.1 max.		
Insulation	More than 100Mohm⋅ <i>μ</i> F	Rated Voltage 60~120 sec.	
Resistance			
Appearance	No abnormal exterior appearance	Visual inspection	
Withstanding	No dielectric breakdown or	250% of the rated voltage	
Voltage	mechanical breakdown		
Temperature	X5R		
Characteristics	(From -55 ℃ to 85 ℃, Capacitance change should be ±15%)		
Adhesive Strength	No peeling shall be occur on the	500g·F, for 10±1 sec.	
of Termination	terminal electrode		
Bending Strength	Capacitance change: within ±12.5%	Bending to the limit (1mm)	
		with 1.0mm/sec.	
Solderability	More than 75% of terminal surface	SnAg3.0Cu0.5 solder	
	is to be soldered newly	245±5℃, 3±0.3sec.	
		(preheating : 80~120 ℃ for 10~30sec.)	
Resistance to	Capacitance change: within ±7.5%	Solder pot : 270±5℃, 10±1sec.	
Soldering heat	Tan δ, IR : initial spec.		

	Performance	Test condition
Vibration Test	Capacitance change: within ±5%	Amplitude : 1.5mm
	Tan δ, IR : initial spec.	From 10Hz to 55Hz (return : 1min.)
		2hours × 3 direction (x, y, z)
Moisture	Capacitance change: within ±12.5%	With rated voltage
Resistance	Tan δ : 0.125 max	40±2℃, 90~95%RH, 500 +12/-0 hours
	IR : More than 12.5MΩ·μF	
High Temperature	Capacitance change: within ±12.5%	With 100% of the rated voltage
Resistance	Tan δ : 0.125 max	Max. operating temperature
	IR : More than 25MΩ·μF	
		1000+48/-0 hours
Temperature	Capacitance change: within ±7.5%	1 cycle condition
Cycling	Tan δ, IR : initial spec.	Min. operating temperature \rightarrow 25 $^{\circ}$ C
		→ Max. operating temperature → 25°C
		5 cycles test

C. Recommended Soldering method :

Reflow (Reflow Peak Temperature : 260+0/-5 $^{\circ}$ C , 10sec. Max)

^{*} For the more detail Specification, Please refer to the Samsung MLCC catalogue.